AlGaInP Laser Diode



ODE-208-192C (Z)

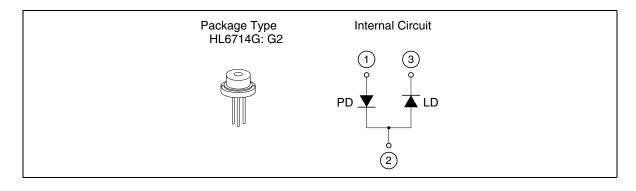
Rev.3 Jan. 2003

Description

The HL6714G is a 0.67 μ m band AlGaInP index-guided laser diode with a multi-quantum well (MQW) structure. It is suitable as a light source for laser beam printers, levelers and various other types of optical equipment. Hermetic sealing of the package assures high reliability.

Features

- Visible light output at wavelengths up to 680 nm
- Single longitudinal mode
- Low astigmatism: 10 µm Typ
- High output power: 10 mW (CW)
- Built-in monitor photodiode





Absolute Maximum Ratings

 $(T_c = 25^{\circ}C)$

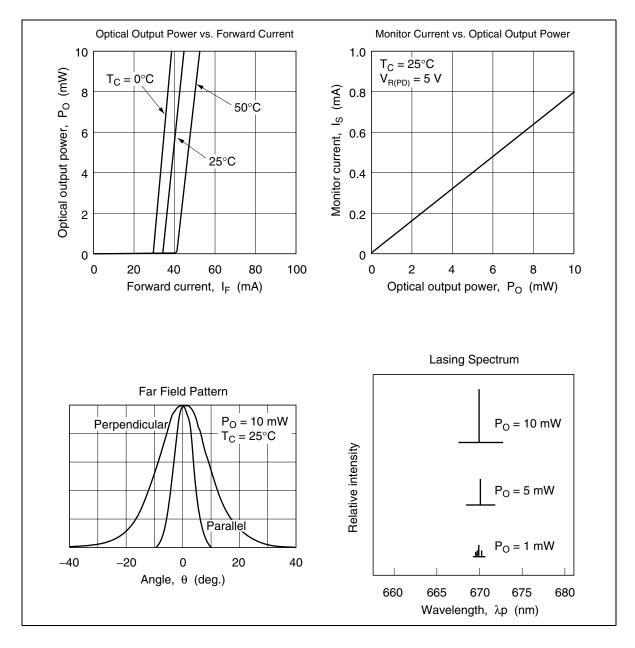
Item	Symbol	Rated Value	Unit	
Optical output power	Po	10	mW	
Pulse optical output power	P _{O(pulse)}	12 *	mW	
LD reverse voltage	V _{R(LD)}	2	V	
PD reverse voltage	V _{r(PD)}	30	V	
Operating temperature	Topr	-10 to +50	°C	
Storage temperature	Tstg	-40 to +85	°C	

Note: Pulse condition : Pulse width $\leq 1 \ \mu s$, duty $\leq 50\%$

Optical and Electrical Characteristics

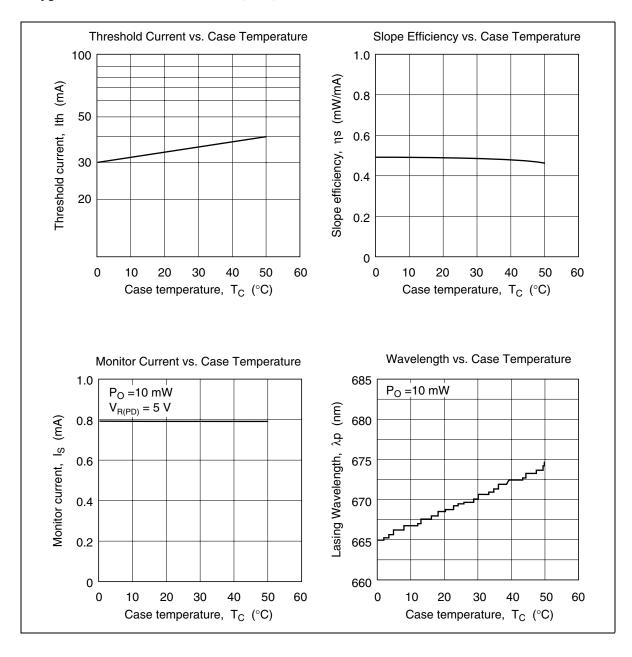
 $(T_c = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	10	_	_	mW	_
Threshold current	lth	20	35	60	mA	—
LD operating voltage	V _{OP}	—	_	2.7	V	$P_o = 10 \text{ mW}$
Slope efficiency	ηs	0.3	0.5	0.8	mW/mA	6 (mW) / (I _(8mW) – I _(2mW))
Beam divergence parallel to the junction	θ//	5	8	11	deg.	$P_o = 10 \text{ mW}, \text{FWHM}$
Beam divergence parpendicular to the junction	θ⊥	18	22	30	deg.	$P_o = 10 \text{ mW}, \text{FWHM}$
Astigmatism	A _s	—	10	_	μ m	P _o = 10 mW, NA = 0.55
Lasing wavelength	λρ	660	670	680	nm	$P_o = 10 \text{ mW}$
Monitor current	I _s	0.3	0.8	1.5	mA	$P_{o} = 10 \text{ mW}, V_{R(PD)} = 5 \text{ V}$



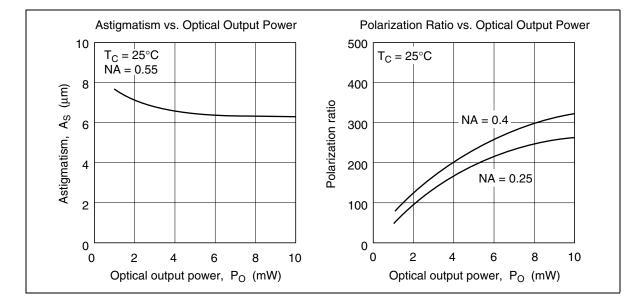
Typical Characteristic Curves





Typical Characteristic Curves (cont)

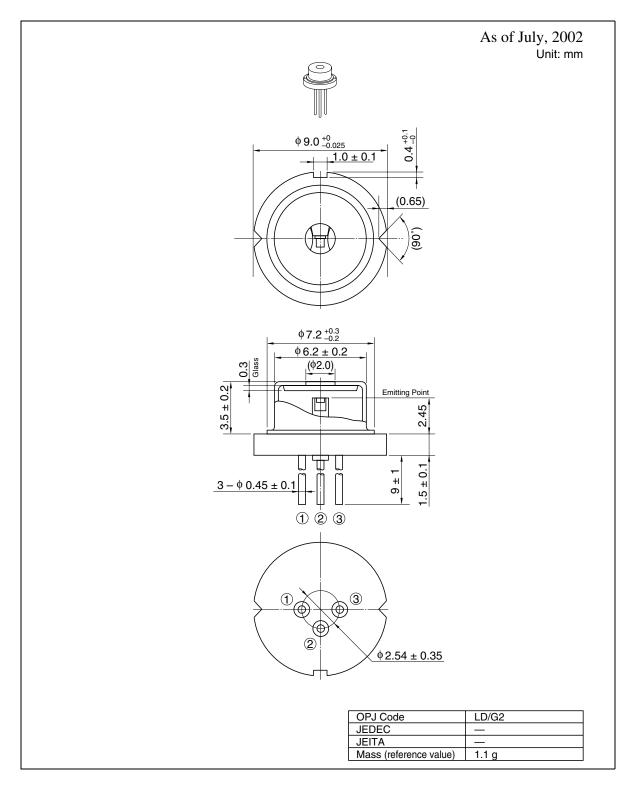




Typical Characteristic Curves (cont)



Package Dimensions





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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product. When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
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Sales Offices



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